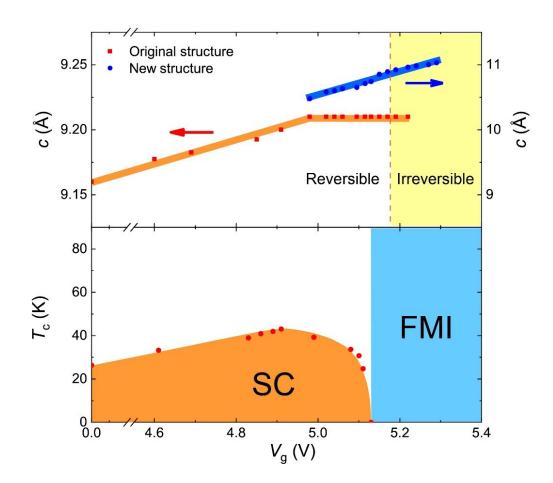


## **Electric-field-controlled superconductorferromagnetic insulator transition**

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The phase diagram of the gate-tuned (Li,Fe)OHFeSe thin flake. Credit: ©Science China Press



High-temperature (Tc) superconductivity typically develops from antiferromagnetic insulators, and superconductivity and ferromagnetism are always mutually exclusive. Recently, Xianhui Chen's group at the University of Science and Technology of China observed an electricfield controlled reversible transition from superconductor to ferromagnetic insulator in (Li,Fe)OHFeSe thin flake. This work offers a unique platform to study the relationship between superconductivity and ferromagnetism in Fe-based superconductors and may provide some clue about understanding the electron pairing mechanism beyond conventional electron-phonon superconductivity.

The relationship between superconductivity and magnetism is key to understanding the electron pairing mechanism beyond conventional electron-phonon superconductivity. Controlling the magnetism near the superconducting region could explain the competing or intertwined electronic states in superconducting and magnetic phases. Modulating carrier density via field electric transistors (FET) is one of the most effective ways to manipulating the collectively ordered electronic states in condensed matter physics. However, only the carrier concentration on the surface of materials can be tuned with conventional gating technique and controlling the <u>charge density</u> in the bulk is plagued due to the Thomas-Fermi screening. Recently, a new type of FET has been developed using solid ion conductor (SIC) as the gate dielectric. In such a SIC-FET, the <u>electric field</u> can not only tune the carrier density to induce electronic phase transitions, but also drive ions into a crystal to transform it from one crystalline phase to another.

By this new developed gating technique, Xianhui Chen's group at University of Science and Technology of China observed an electricfield controlled reversible transition from superconductor to ferromagnetic insulator in (Li,Fe)OHFeSe thin flake. Using SIC-FET, Li ions can be driven into or extracted out from the (Li,Fe)OHFeSe thin flake by electric field. When the Li ions are initially driven into the thin



flake, Li ions replace the Fe in the hydroxide layers and the Fe ions expelled by Li can migrate away from the hydroxide layers to fill the vacancies in the selenide layers. Once the vacancies are filled, the thin flake achieves the optimal Tc ~ 43 K. With further Li injection, the Fe ions extruded from the hydroxide layers migrate to the interstitial sites, and then the interstitial Fe ions become ordered and eventually lead to a long-range ferromagnetic order. So, a dome-shaped superconducting phase with optimal Tc (= 43 K) is continuously tuned into a ferromagnetic insulating phase, which exhibits an electric-fieldcontrolled quantum critical behavior. The device is fabricated on a solid ion conductor, which can reversibly manipulate collectively ordered <u>electronic states</u> of the materials and stabilize new metastable structures by electric field. This work paves a way to access metastable phases and to control structural <u>phase</u> transformation as well as <u>physical properties</u> by the electric field.

These surprising findings offer a unique platform to study the relationship between <u>superconductivity</u> and ferromagnetism in Fe-based superconductors. This work also demonstrates the superior performance of SIC-FET in regulating the physical properties of layered crystals and its potential applications for multifunctional devices.

**More information:** Likuan Ma et al, Electric-field controlled superconductor-ferromagnetic insulator transition, *Science Bulletin* (2019). DOI: 10.1016/j.scib.2019.04.022

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